

Using S-Parameters for the Design of EMC Filters

**OMICRON 13th Power Analysis
& Design Symposium**



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Organized by,

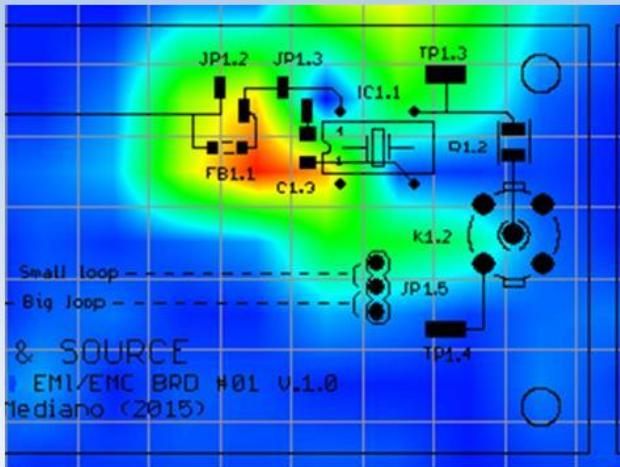


2024

April 17th, 2024



A High Frequency Lab for design, diagnostic, troubleshooting and training



Interferences (EMI)
Electromagnetic Compatibility (EMC)
Signal Integrity (SI)
Radiofrequency(RF)

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About the speaker ...

Prof. Arturo Mediano

*Teaching Professor in EMI/EMC/RF/SI
I3A, University of Zaragoza (SPAIN)*

Arturo Mediano is the founder of The HF-Magic Lab®, a specialized laboratory for design, diagnostic, troubleshooting, and training in the EMI/EMC, Signal Integrity, and RF fields at I3A (University of Zaragoza).

He received his M.Sc. (1990) and his Ph. D. (1997) in Electrical Engineering from the University of Zaragoza (Spain), where he has held a teaching professorship in EMI/EMC/RF/SI since 1992.

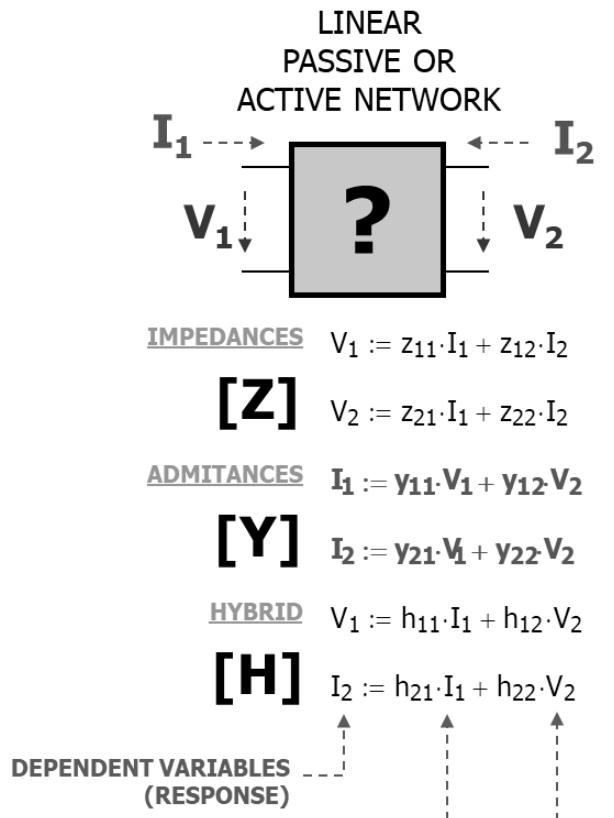
For more than 30 years Arturo has been involved in R&D projects with many companies in the EMI/EMC, Signal Integrity and RF fields for communications, industry, medical, and scientific applications. He regularly shares his knowledge and expertise with students and engineers in teaching courses and seminars.



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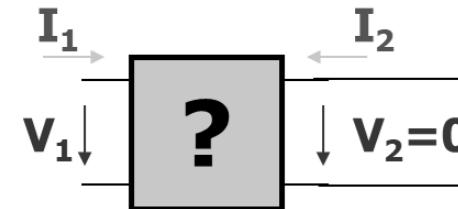
S parameters: introduction.



EXTRACTION OF Z, H & Y parameters

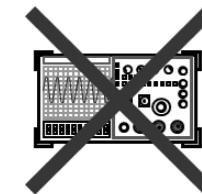
Example:

$$h_{11} := \left. \frac{V_1}{I_1} \right|_{V_2=0}$$



High frequency limitations

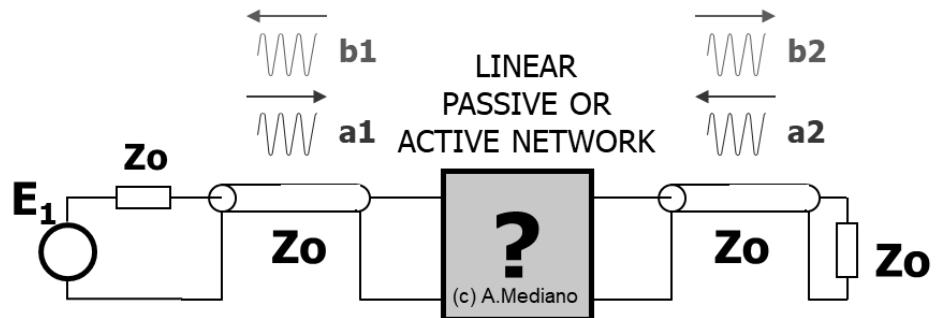
- a) Limitations for instruments to measure **V** and **I**.
- b) Shorts and Opens difficult to implement.
- c) Some active networks can oscillate with shorts or opens in their ports.



S parameters: introduction

Scattering parameters

Agilent AN 154
S-Parameter Design
Application Note



Forward and reflected signals are variables result from linear combination of voltage and current in test ports:

Independent variables are normalized INCIDENT voltages:

$$a_1 := \frac{V_{i1}}{\sqrt{Z_0}}$$

$$a_2 := \frac{V_{i2}}{\sqrt{Z_0}}$$

Dependent variables are normalized REFLECTED voltages:

$$b_1 := \frac{V_{r1}}{\sqrt{Z_0}}$$

$$b_2 := \frac{V_{r2}}{\sqrt{Z_0}}$$

$(|a_1|)^2$ = Incident power on input port

$(|a_2|)^2$ = Incident power on output port (power reflected from load)

$(|b_1|)^2$ = Reflected power on input port =
= Power incident on input port - Power delivered to input port

$(|b_2|)^2$ = Incident power to load

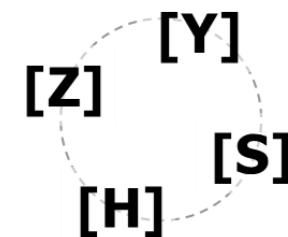
[b]=[S]×[a]

$$b_1 := S_{11} \cdot a_1 + S_{12} \cdot a_2$$

$$b_2 := S_{21} \cdot a_1 + S_{22} \cdot a_2$$

IMPORTANT IDEAS

- The system is defined with s_{11} , s_{12} , s_{21} , s_{22} and Z_0 .
- S parameters are complex numbers
- It is easy to convert parameters:



S parameters: meaning

s11 y s22 ⇒ INPUT AND OUTPUT REFLECTION COEFFICIENTS

$$s_{11} := \frac{b_1}{a_1} \text{ when } a_2 := 0 \quad s_{11} := \text{Input reflection coefficient when output port terminated in } Z_0$$

$$s_{22} := \frac{b_2}{a_2} \text{ when } a_1 := 0 \quad s_{22} := \text{Output reflection coefficient when input port terminated in } Z_0$$

ALWAYS PORTS TERMINATED IN CHARACTERISTIC IMPEDANCE (i.e. 50 OHMS)

s21 ⇒ FORWARD GAIN/INSERTION LOSS

$$s_{21} := \frac{b_2}{a_1} \text{ when } a_2 := 0 \quad s_{21} := \text{Forward transmission gain with output port terminated in } Z_0$$

s12 ⇒ REVERSE GAIN

$$s_{12} := \frac{b_1}{a_2} \text{ when } a_1 := 0 \quad s_{12} := \text{Reverse transmission gain with input port terminated in } Z_0$$

Example: RF LP commercial filter

Coaxial

Low Pass Filter

50Ω DC to 48 MHz

Maximum Ratings

Operating Temperature	-55°C to 100°C
Storage Temperature	-55°C to 100°C
RF Power Input	0.5W max.

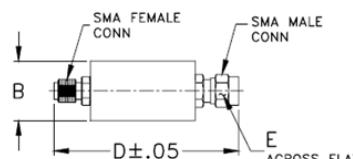
Features

- good attenuation rate, 1.35 typ. 20dB/ 3dB BW ratio
- rugged shielded case
- other SLP models available with wide selection of cut-off frequencies

Applications

- lab use
- test equipment
- video equipment

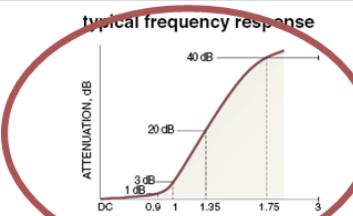
Outline Drawing



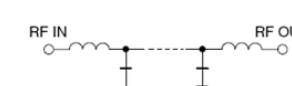
Low Pass Filter Electrical Specifications

PASSBAND (MHz) (loss < 1 dB)	f _{co} (MHz) Nom. (loss 3 dB)	STOPBAND (MHz) (loss > 20 dB)	VSWR (:1)
DC-48	55	70-90 90-200	Passband Typ. 1.7
			Stopband Typ. 18

typical frequency response



electrical schematic



SLP-50+
SLP-50



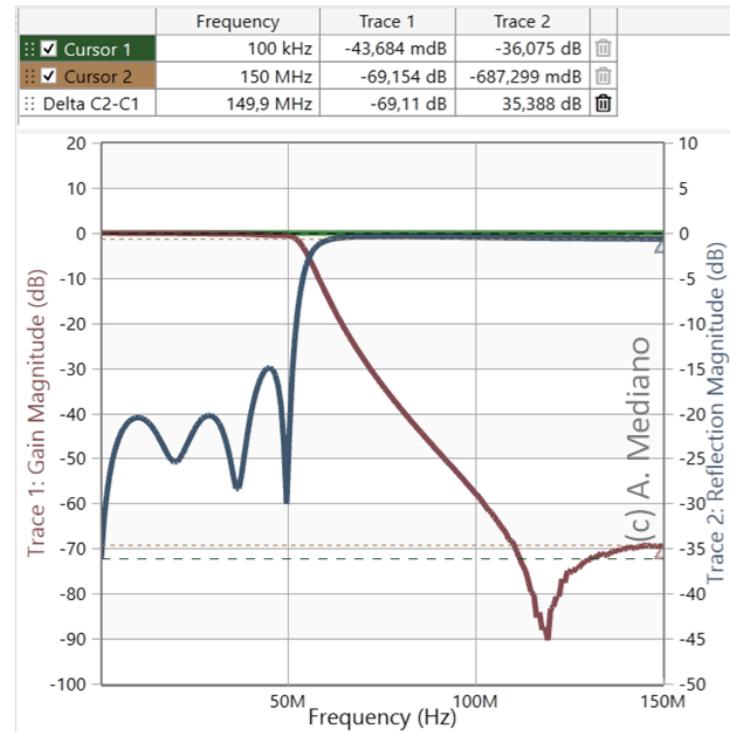
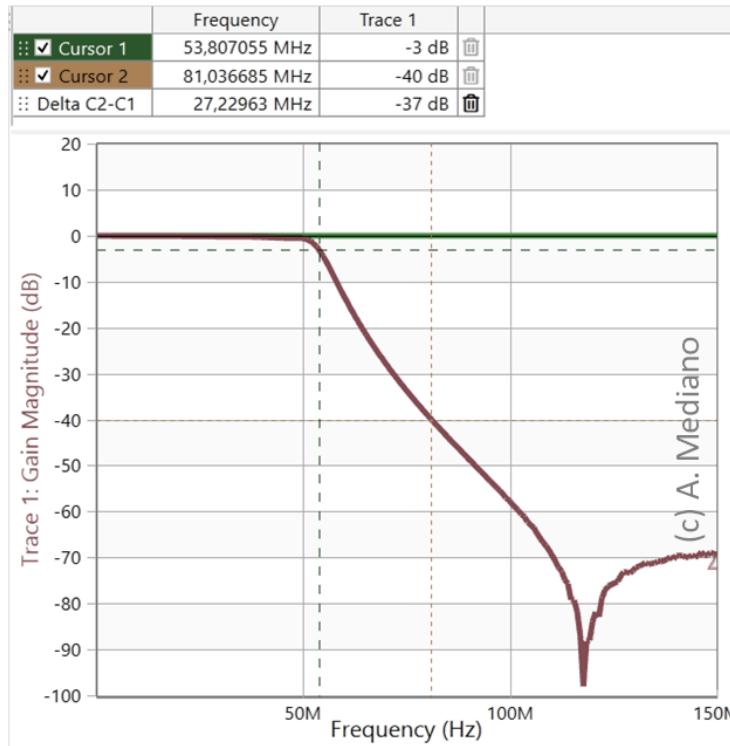
CASE STYLE: FF99

Connectors	Model	Price	Qty.
SMA	SLP-50(+)	\$34.95 ea. (1-9)	

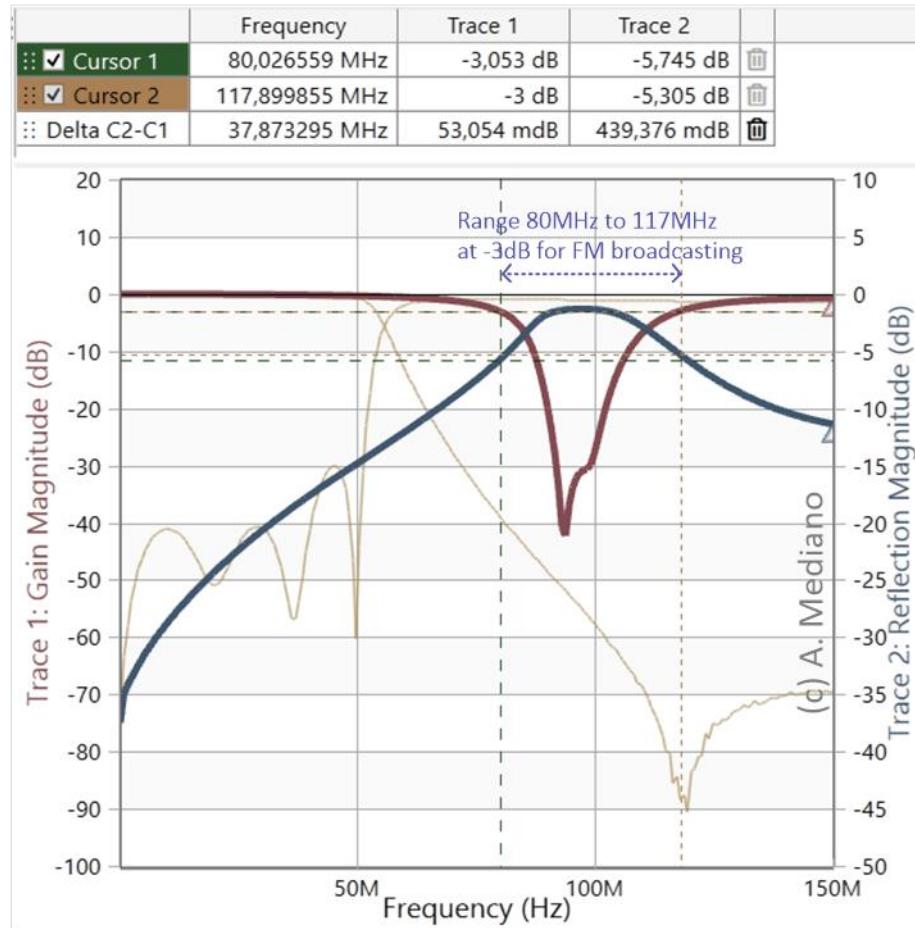
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

Example: LP filter response



Example: Comparing a bandreject filter



Commercial filters: an important point

For RF/wireless applications terminal impedances are usually 50Ω and the filter response is easy to characterize and specify.

What about EMI/EMC filters?

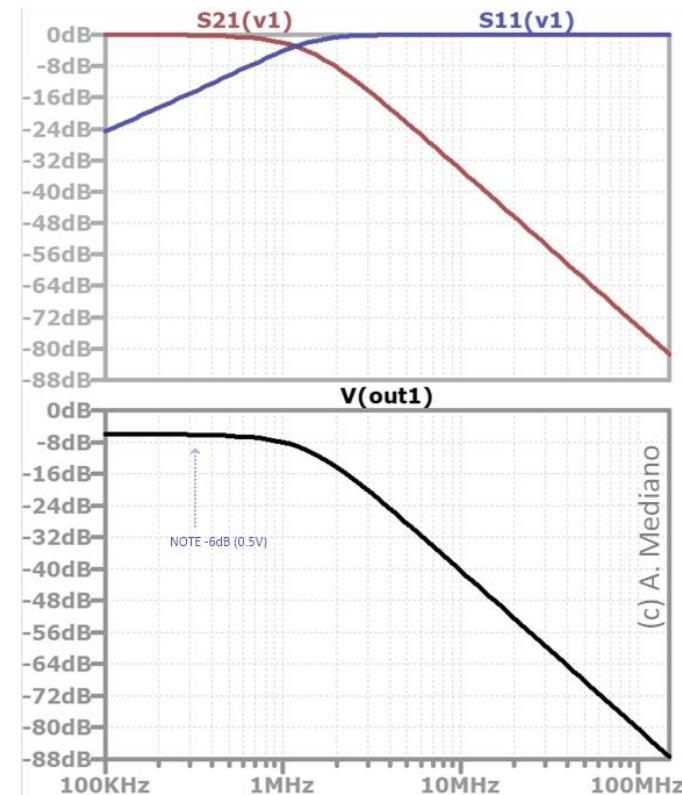
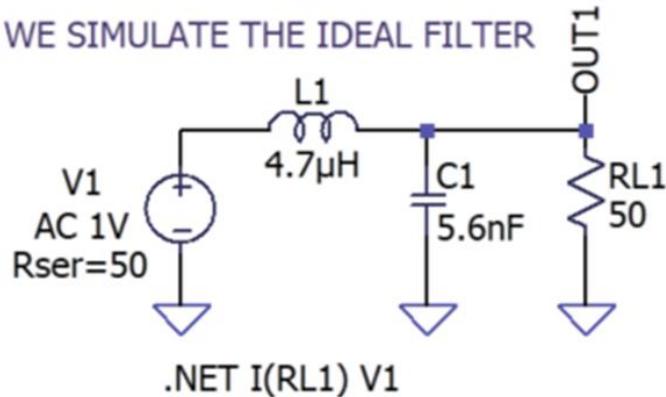
Remember filter response is dependent of terminal impedances and **we do not know how they are in EMI applications !!!!!**

Example: LP EMI filter

Note that, in EMI, terminal impedances are unknown!!!!!!
Let's think the user design the filter with 50-50ohms:

.ac dec 101 100k 150MEG

1) WE SIMULATE THE IDEAL FILTER



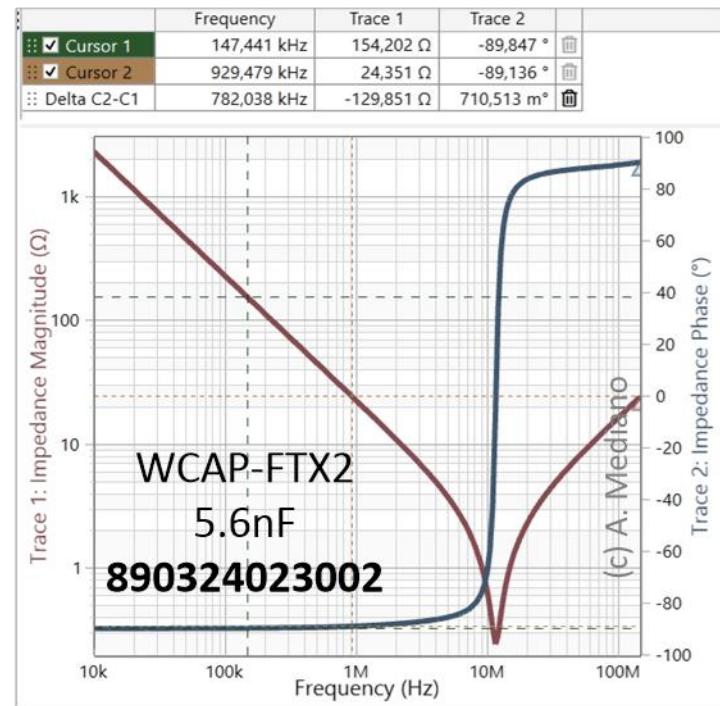
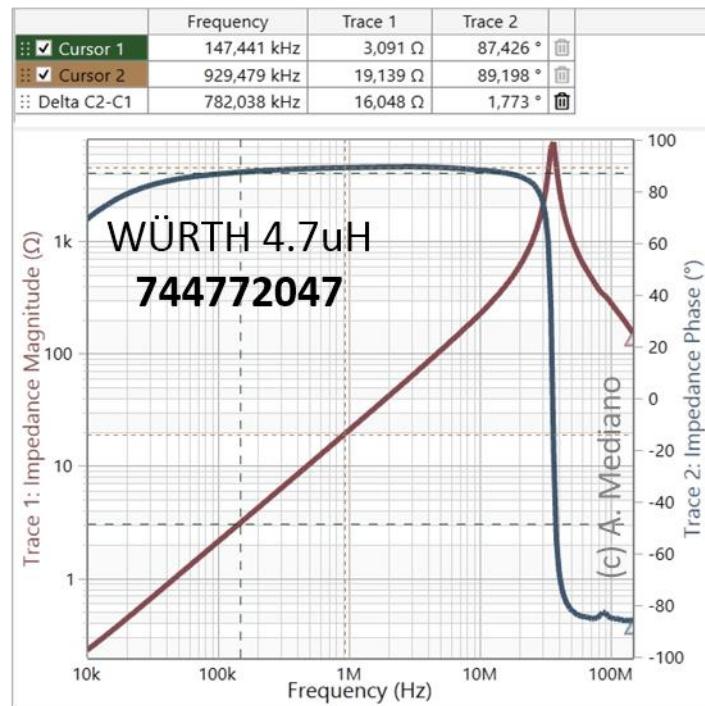
Example: LP EMI filter and components



WÜRTH
4.7uH
744772047

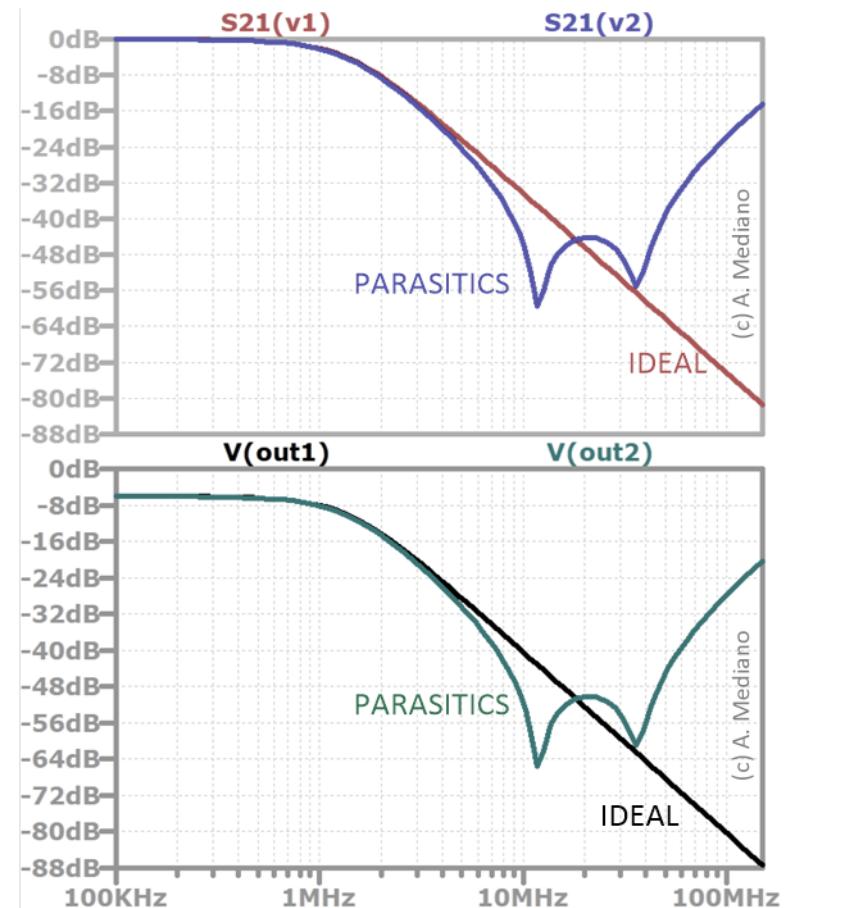
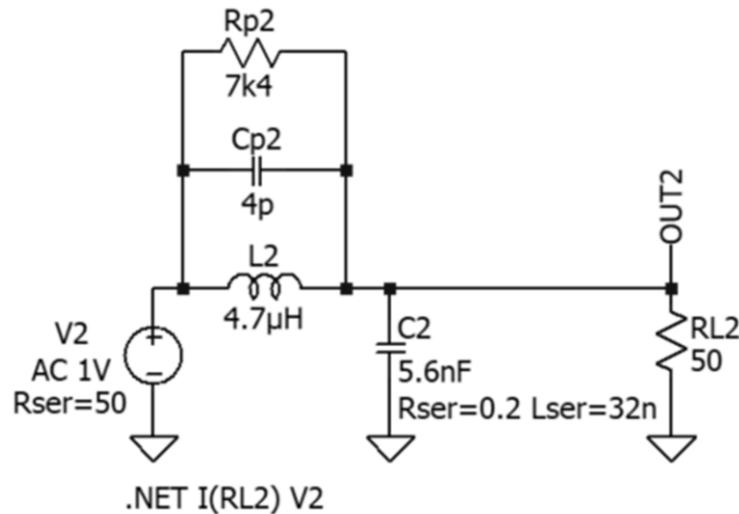


WCAP-FTX2
5.6nF
890324023002

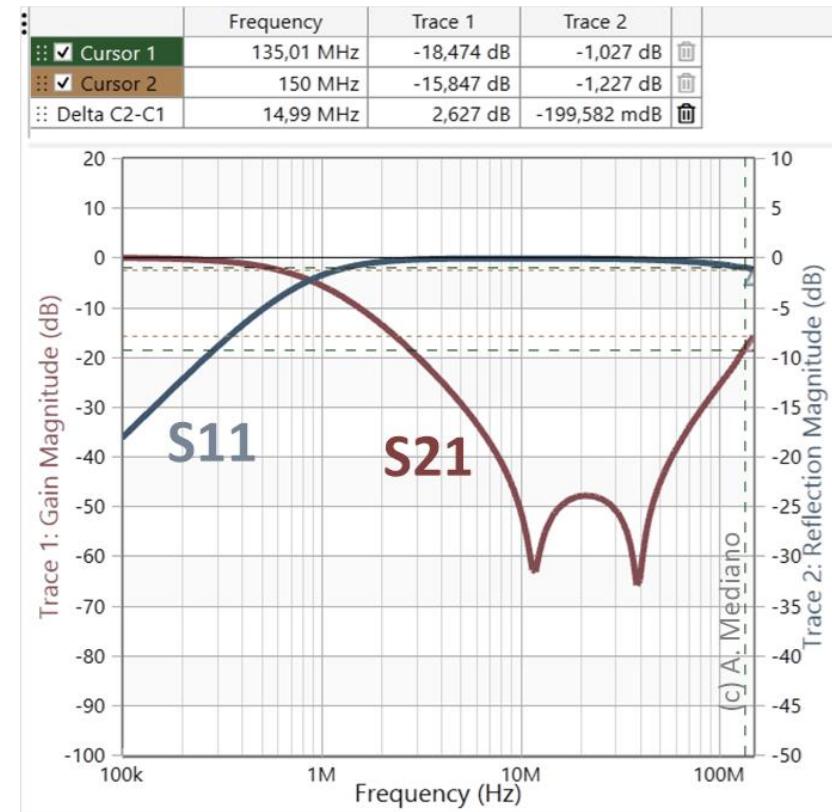


Example: LP EMI filter and parasitics

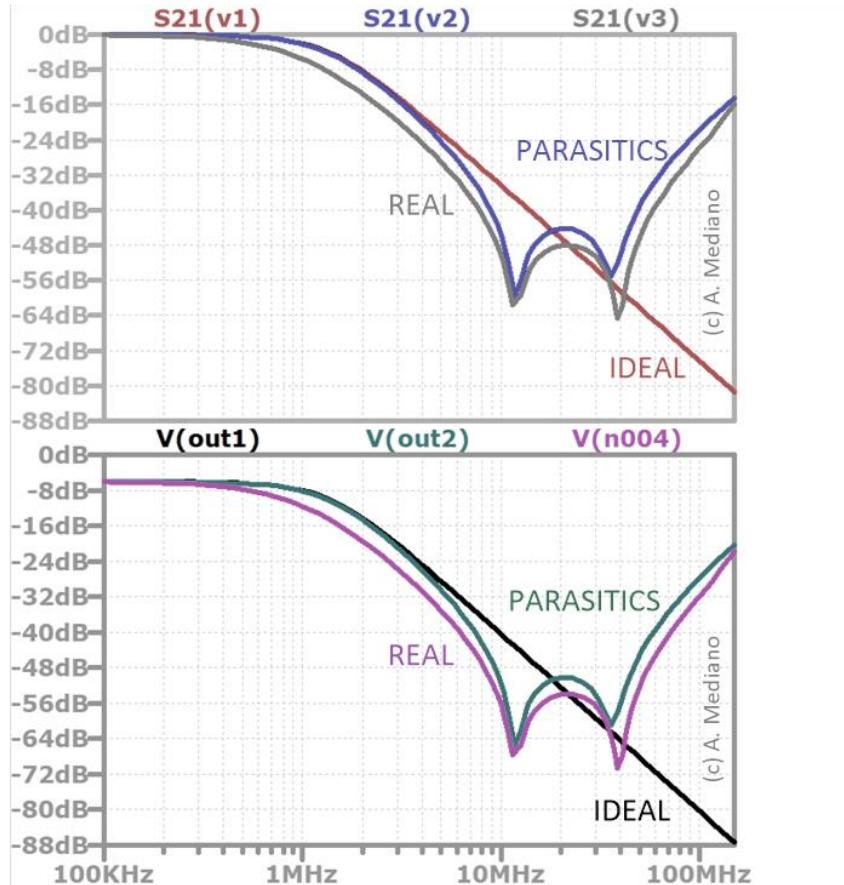
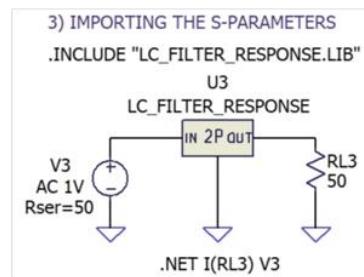
2) WE ADD PARASITICS



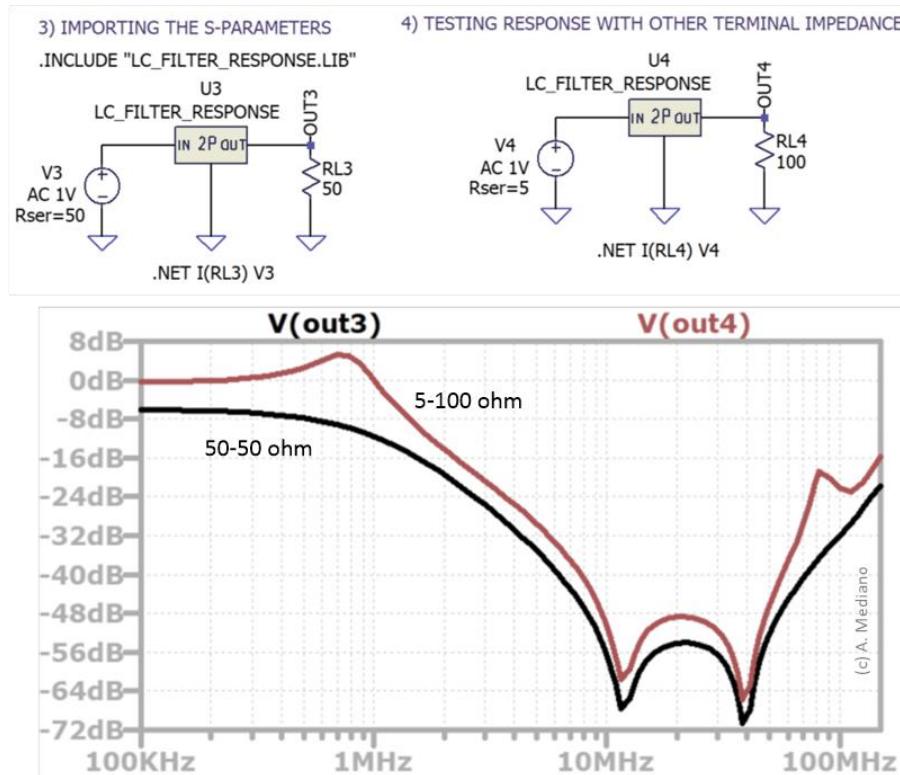
Example: LP EMI filter real response



Example: LP EMI filter response and LTSPICE

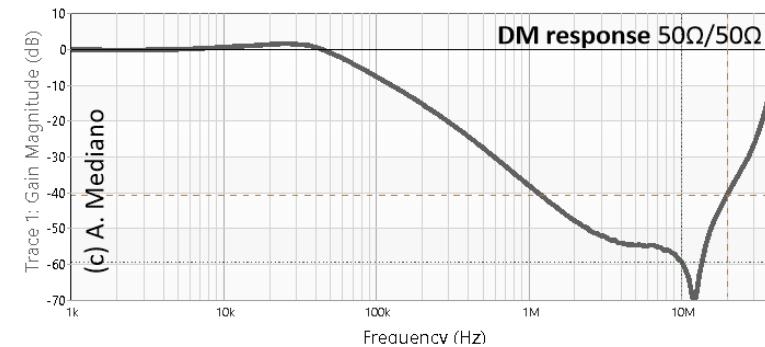
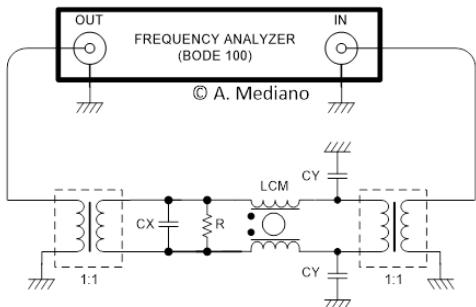


Example: Analyzing terminal impedances

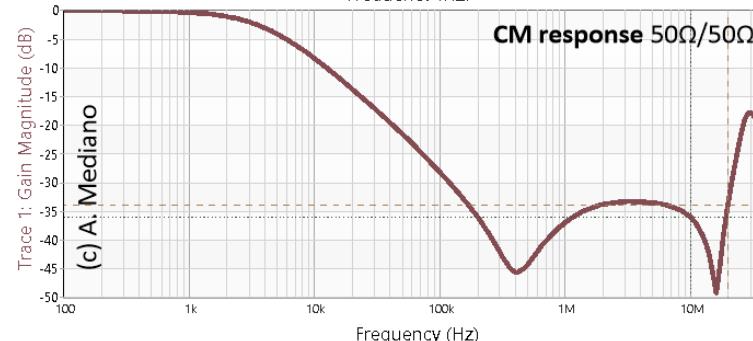
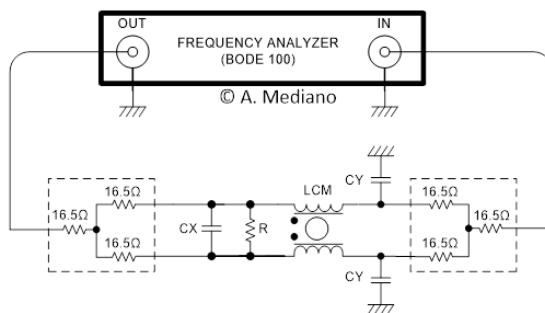


Measuring EMC filters: DM and CM

MEASURING DM



MEASURING CM



Mar 18



interferencetechnology.com

Review of the EMC Filters Kit from Würth Elektronik by Arturo Mediano.



THANK YOU!



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